

# **Noninverting 3-State Buffer**

## MC74VHC1G125, MC74VHC1GT125

The MC74VHC1G125 / MC74VHC1GT125 is a single non-inverting 3-state buffer in tiny footprint packages. The MC74VHC1G125 has CMOS-level input thresholds while the MC74VHC1GT125 has TTL-level input thresholds.

The internal circuit is composed of three stages, including a buffered 3-state output which provides high noise immunity and stable output.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. Some output structures also provide protection when  $V_{CC} = 0$  V and when the output voltage exceeds  $V_{CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

### **Features**

- Designed for 2.0 V to 5.5 V V<sub>CC</sub> Operation
- 3.5 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

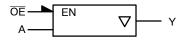


Figure 1. Logic Symbol

### MARKING DIAGRAMS



SC-88A DF SUFFIX CASE 419A





SC-74A DBV SUFFIX CASE 318BQ





SOT-953 P5 SUFFIX CASE 527AE





UDFN6 1.45 x 1.0 CASE 517AQ





UDFN6 1.2 x 1.0 CASE 517AA





UDFN6 1.0 x 1.0 CASE 517BX



XX = Specific Device Code

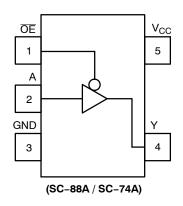
M = Date Code\*= Pb-Free Package

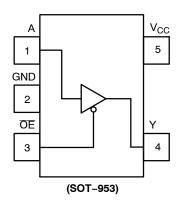
(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 8 of this data sheet.





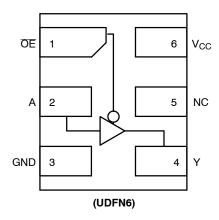


Figure 2. Pinout (Top View)

### **PIN ASSIGNMENT** (SC-88A / SC-74A)

Pin	Function
1	ŌĒ
2	А
3	GND
4	Y
5	V <sub>CC</sub>

### PIN ASSIGNMENT (SOT-953)

Pin	Function
1	Α
2	GND
3	ŌĒ
4	Y
5	V <sub>CC</sub>

### PIN ASSIGNMENT (UDFN)

Pin	Function
1	ŌĒ
2	Α
3	GND
4	Υ
5	NC
6	V <sub>CC</sub>

### **FUNCTION TABLE**

Inp	Output	
ŌĒ	Α	Υ
L	L	L
L	Н	Н
Н	Х	Z

X = Don't Care

### **MAXIMUM RATINGS**

Symbol	Characteristics		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	Tri-	e (High or Low State) State Mode (Note 1) vn Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current	±25	mA	
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin	±50	mA	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$ heta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-553 SOT-953 UDFN6	377 320 324 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SC-74A SOT-553 SOT-953 UDFN6	332 390 386 491 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating Ox	ygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model narged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri–stated.

Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.

<sup>4.</sup> Tested to EIA/JESD78 Class II.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	2.0	5.5	V
$V_{IN}$	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode ( $V_{\rm CC}$ = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $V_{CC} = 2.0 \text{ V} \\ V_{CC} = 2.3 \text{ V to } 2.7 \text{ V} \\ V_{CC} = 3.0 \text{ V to } 3.6 \text{ V} \\ V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS (MC74VHC1G125)

		Test	Vcc	7	_A = 25°	Ö	-40°C ≤	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.5	-	-	1.5	-	1.5	-	V
	Voltage		3.0	2.1	-	-	2.1	-	2.1	-	
			4.5	3.15	-	-	3.15	-	3.15	-	
			5.5	3.85	-	-	3.85	-	3.85	-	
V <sub>IL</sub>	Low-Level Input		2.0	_	-	0.5	-	0.5	-	0.5	V
	Voltage		3.0	-	-	0.9	-	0.9	-	0.9	
			4.5	-	-	1.35	=	1.35	-	1.35	
			5.5	-	-	1.65	=	1.65	-	1.65	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OH} &= -50  \mu\text{A} \\ I_{OH} &= -50  \mu\text{A} \\ I_{OH} &= -50  \mu\text{A} \\ I_{OH} &= -4  m\text{A} \\ I_{OH} &= -8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –		1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 4  m\text{A} \\ I_{OL} = 8  m\text{A} \end{array}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	5.5	_	-	±0.25	-	±2.5	_	±2.5	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0.0	_	-	1.0	-	10	_	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μΑ

### DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT125)

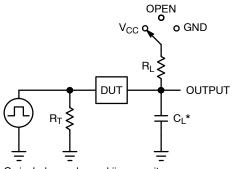
		Test	v <sub>cc</sub>	1	_ <sub>A</sub> = 25°	С	-40°C ≤	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	T <sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.0	-	-	1.0	_	1.0	-	V
	Voltage		3.0	1.4	-	-	1.4	-	1.4	-	1
			4.5	2.0	-	-	2.0	-	2.0	-	1
			5.5	2.0	_	-	2.0	_	2.0	-	
$V_{IL}$	Low-Level Input		2.0	-	-	0.28	-	0.28	-	0.28	V
	Voltage		3.0	-	-	0.45	=	0.45	-	0.45	
			4.5	-	ı	0.8	-	0.8	-	0.8	
			5.5	-	-	0.8	_	0.8	-	0.8	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -4  m\text{A} \\ &I_{OH} = -8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 -		1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	>
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	<b>V</b>
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	_	±1.0	μΑ
I <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	5.5	-	-	±0.25	-	±2.5	-	±2.5	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	_	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	_	40	μΑ
I <sub>CCT</sub>	Increase in Quiescent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

### **AC ELECTRICAL CHARACTERISTICS**

				T	A = 25°	С	-40°C ≤ 7	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	_	4.5	8.0	-	9.5	_	12.0	ns
t <sub>PHL</sub>	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	6.4	11.5	-	13.0	_	16.0	
	,	C <sub>L</sub> = 15 pF	4.5 to 5.5	_	3.5	5.5	-	6.5	_	8.5	
		C <sub>L</sub> = 50 pF		_	4.5	7.5	-	8.5	_	10.5	
t <sub>PZL</sub> ,	Output Enable	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	4.5	8.0	_	9.5	_	11.5	ns
<sup>t</sup> PZH	Time, OE to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	6.4	11.5	-	13.0	_	15.0	
	,	C <sub>L</sub> = 15 pF	4.5 to 5.5	_	3.5	5.1	-	6.0	_	8.5	
		C <sub>L</sub> = 50 pF		-	4.5	7.1	_	8.0	_	10.5	
t <sub>PLZ</sub> ,	Output Disable	C <sub>L</sub> = 15 pF	3.0 to 3.6	_	6.5	9.7	-	11.5	_	14.5	ns
t <sub>PHZ</sub>	Time, OE to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		-	8.0	13.2	_	15.0	_	18.0	
	,	C <sub>L</sub> = 15 pF	4.5 to 5.5	-	4.8	6.8	_	8.0	_	10.0	
		C <sub>L</sub> = 50 pF		-	7.0	8.8	_	10.0	_	12.0	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	_	10	_	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	ı	-	-	-	-	pF

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	8.0	pF

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



X = Don't Care

Test

 $t_{PLH} / t_{PHL}$ 

 $t_{PLZ} / t_{PZL}$ 

t<sub>PHZ</sub> / t<sub>PZH</sub>

**Switch** 

**Position** 

Open

 $V_{CC}$ 

GND

 $R_L, \Omega$ 

1 k

1 k

 $C_L$ , pF

See AC Characteristics Table

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 3. Test Circuit

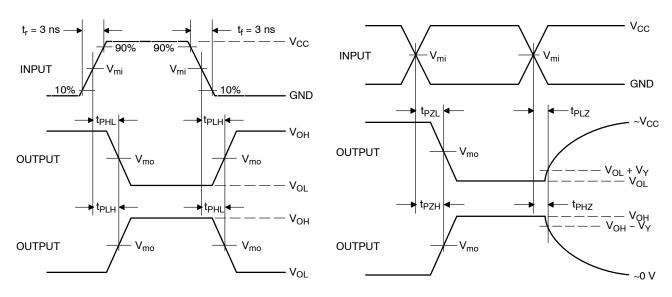


Figure 4. Switching Waveforms

		V <sub>m</sub>		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

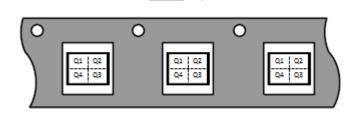
### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G125DFT1G	SC-88A	W0	Q2	3000 / Tape & Reel
MC74VHC1G125DFT2G	SC-88A	W0	Q4	3000 / Tape & Reel
MC74VHC1G125DFT1G-Q*	SC-88A	W0	Q2	3000 / Tape & Reel
MC74VHC1G125DFT2G-Q*	SC-88A	W0	Q4	3000 / Tape & Reel
MC74VHC1GT125DFT1G	SC-88A	W1	Q2	3000 / Tape & Reel
MC74VHC1GT125DFT2G	SC-88A	W1	Q4	3000 / Tape & Reel
MC74VHC1GT125DFT1G-Q*	SC-88A	W1	Q2	3000 / Tape & Reel
MC74VHC1GT125DFT2G-Q*	SC-88A	W1	Q4	3000 / Tape & Reel
MC74VHC1G125DBVT1G	SC-74A	W0	Q4	3000 / Tape & Reel
MC74VHC1GT125DBVT1G	SC-74A	W1	Q4	3000 / Tape & Reel
MC74VHC1G125P5T5G	SOT-953	Т	Q2	8000 / Tape & Reel
MC74VHC1GT125P5T5G (Contact <b>onsemi</b> )	SOT-953	TBD	Q2	8000 / Tape & Reel
MC74VHC1G125MU1TCG (Contact <b>onsemi</b> )	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT125MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	D	Q4	3000 / Tape & Reel
MC74VHC1GT125MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	7	Q4	3000 / Tape & Reel
MC74VHC1G125MU3TCG (Contact <b>onsemi</b> )	UDFN6, 1.0 x 1.0, 0.35P	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT125MU3TCG	UDFN6, 1.0 x 1.0, 0.35P	L	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### Pin 1 Orientation in Tape and Reel

### Direction of Feed



<sup>\*-</sup>Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



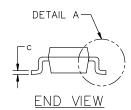


### SC-74A-5 3.00x1.50x0.95, 0.95P CASE 318BQ ISSUE C

**DATE 26 FEB 2024** 

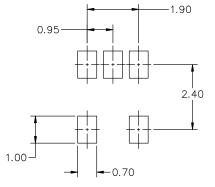


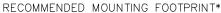
- 1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.



DIM			
DIN	MIN.	NOM.	MAX.
Α	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2	(	0.95 REF	
Ь	0.25	0.37	0.50
C	0.10	0.18	0.26
D	2.85	3.00	3.15
E	:	2.75 BSC	;
E1	1.35	1.50	1.65
е	(	0.95 BSC	;
L	0.20	0.40	0.60
L1	0.62 REF.		
L2	0.25 BSC		;
Θ	0,	5°	10°

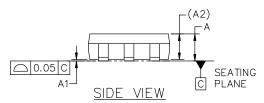
**MILLIMETERS** 

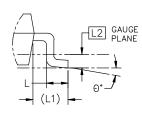




\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

# 





DETAIL "A" SCALE 2:1

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

DESCRIPTION:	SC-74A-5 3.00x1.50x0.95,	0.95P	PAGE 1 OF 1
DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLEI	

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





0



### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

**DATE 11 APR 2023** 

### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE, NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

DIM	MILLIMETERS		RS
INITU	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3		0.20 REF	•
b	0.10	0.20	0.30
C	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30

5X b

◆ 0.2 M B M

- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

<u> </u>	0.50	5

### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

### **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	<ol><li>SOURCE 1</li></ol>	3. CATHODE 2
4. COLLECTOR	<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE 2</li></ol>	4. GATE 1	4. CATHODE 3
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE 1</li></ol>	5. GATE 2	5. CATHODE 4
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	Note: Please refer to datasheet for
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	atula callout. If atula tupa is not called
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	style callout. If style type is not called
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	out in the datasheet refer to the device
4. COLLECTOR	<ol><li>COLLECTOR</li></ol>	4. BASE	4. ANODE	datasheet pinout or pin assignment.
<ol><li>COLLECTOR 2/BASE 1</li></ol>	5. COLLECTOR	5. EMITTER	5. ANODE	datasheet pinout of pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)		PAGE 1 OF 1

5. EMITTER

onsemi and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

5. COLLECTOR 2/BASE 1



D

△ aaa C

Pin 1

### UDFN6, 1.20x1.00x0.50, 0.40P CASE 517AA **ISSUE E**

**DATE 09 MAY 2025** 

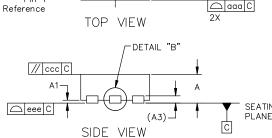
### NOTES:

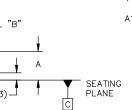
Exposed

- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018. 1
- CONTROLLING DIMENSION: MILLIMETERS.

·Mold Compound

- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
- COPLANARITY APPLIES TO TH EXPOSED PAD AS WELL AS THE TERMINALS.

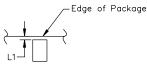




В

Ε

DETAIL "A"



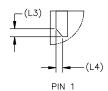
DETAIL "A" Scale 2:1 Bottom View (Optional)

DETAIL "B"

Scale 2:1

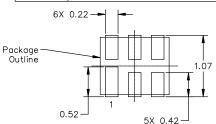
Side View

(Optional)



Chamfer Dimension

**MILLIMETERS** DIM MIN NOM MAX0.45 0.55 Α 0.50 Α1 0.00 0.05 \_\_\_\_ 0.127 REF А3 0.15 0.20 0.25 b D 1.20 BSC Ε 1.00 BSC 0.40 BSC е 0.30 0.35 0.40 L L1 0.00 \_\_\_ 0.15 L2 0.40 0.45 0.50 L3 0.14 REF L4 0.116 REF TOLERANCE FORM & POSITION aaa 0.10 bbb 0.10 CCC 0.10 ddd 0.05 eee 0.08



### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

L2		
†		
	16 4	
01/ 1	e	
6X b bbb C A B	►    <del>-</del> - 	
l * ldddlCl	OTTOM VIEW	

GENERIC			
MARKII	NG DIA	AGRAM*	
	XXM		

CENEDIC

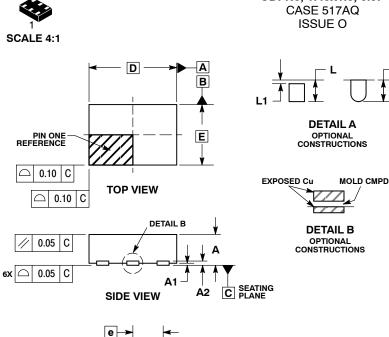
XX = Specific Device Code = Date Code М

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON22068D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	UDFN6, 1.20x1.00x0.50, 0.4	UDFN6, 1.20x1.00x0.50, 0.40P	

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





6X L

6X b

Ф

0.10 | C | A | B

0.05 C NOTE 3

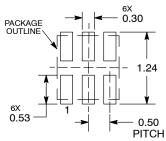
## UDFN6, 1.45x1.0, 0.5P CASE 517AQ

**DATE 15 MAY 2008** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A2	0.07	REF	
b	0.20	0.30	
D	1.45 BSC		
Е	1.00 BSC		
е	0.50 BSC		
Ĺ	0.30	0.40	
L1		0.15	

### **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

### **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 



Χ = Specific Device Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98AON30313E	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED"	
DESCRIPTION:	UDFN6, 1.45x1.0, 0.5P		PAGE 1 OF 1

onsemi and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.







UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

**DATE 18 MAY 2011** 

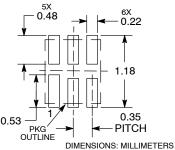


- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF
- BURRS AND MOLD FLASH.

	MILLIMETERS	
DIM	MIN MAX	
Α	0.45	0.55
A1	0.00	0.05
A3	0.13	REF
b	0.12	0.22
D	1.00 BSC	
E	1.00 BSC	
е	0.35 BSC	
L	0.25	0.35
L1	0.30	0.40

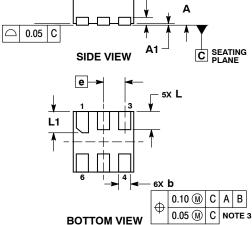
NOTES:

### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# AB PIN ONE REFERENCE E 0.10 0.10 C **TOP VIEW** 0.05 C



### **GENERIC MARKING DIAGRAM\***



X = Specific Device Code

M = Date Code

DOCUMENT NUMBER:	98AON56787E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6, 1x1, 0.35P		PAGE 1 OF 1

onsemi and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

MILLIMFTERS

 $N\square M$ 

0.37

0.15

0.12

1.00

0.80

0.35 BSC

1.00

0.175

0.10

(REF)

-0.350

0.075

-0.200

MIN

0.34

0.10

0.07

0.95

0.75

0.95

0.125

0.05

DIM

Α

b

C

 $\mathbb{D}$ 

E

9 Н

L2

L3





### SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE **ISSUE F**

**DATE 17 JAN 2024** 

MAX

0.40

0.20

0.17

1.05

0.85

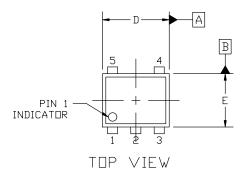
1.05

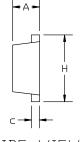
0.225

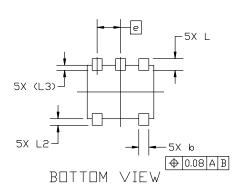
0.15

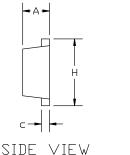
### NOTES:

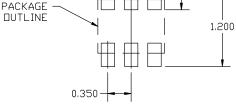
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.











### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

### **GENERIC MARKING DIAGRAM\***



= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON26457D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 1

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

### ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS:** 

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales